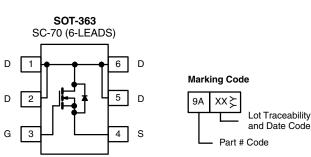
SQ1420EEH



Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$	0.140			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 V$	0.200			
I _D (A)	1.6			
Configuration	Single			

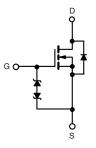


FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET® Power MOSFET
- AEC-Q101 Qualified^d
- 100 % Rg Tested
- Typical ESD Protection: 800 V
- Compliant to RoHS Directive 2002/95/EC



COMPLIANT HALOGEN



N-Channel MOSFET

ORDERING INFORMATION

Top View

Package	SC-70
Lead (Pb)-free and Halogen-free	SQ1420EEH-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20	v	
Continuous Drain Current ^a	T _C = 25 °C	- I _D -	1.6	A	
	T _C = 125 °C		1.6		
Continuous Source Current (Diode Conduction) ^a		I _S	1.6	A	
Pulsed Drain Current ^b		I _{DM}	6.7		
Maximum Power Dissipation ^b	T _C = 25 °C	_	3.3	W	
Maximum Power Dissipation	T _C = 125 °C	P _D	1.1	VV	
Operating Junction and Storage Temperature F	Range	T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	125	°C/W		
Junction-to-Foot (Drain)		R _{thJF}	45	0/10		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.

SQ1420EEH



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							I
Drain-Source Breakdown Voltage	V _{DS}	V _{GS}	$V_{GS} = 0, I_D = 250 \ \mu A$		-	-	v
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	: V _{GS} , I _D = 250 μA	1.5	2.0	2.5	v
Gate-Source Leakage		V _{DS} =	0 V, $V_{GS} = \pm 12$ V	-	-	± 500	nA
Gale-Source Leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20$ V	-	-	1	mA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	1	-	-	Α
		V _{GS} = 10 V	I _D = 1.2 A	-	0.100	0.140	Ω
Drain Source On State Desistence?	P	V _{GS} = 10 V	I _D = 1.2 A, T _J = 125 °C	-	-	0.245	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 1.2 A, T _J = 175 °C	-	-	0.308	
		$V_{GS} = 4.5 V$	I _D = 1 A	-	0.152	0.200	
Forward Transconductanceb	9 _{fs}	V _{DS}	= 15 V, I _D = 1 A	-	2.9	-	S
Dynamic ^b	·						
Input Capacitance	C _{iss}			-	172	215	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	36	45	pF
Reverse Transfer Capacitance	C _{rss}			-	24	30	1
Total Gate Charge ^c	Qg			-	2.7	4	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 4.5 V$	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 2.8 \text{ A}$	-	0.7	-	nC
Gate-Drain Charge ^c	Q _{gd}			-	1.4	-]
Gate Resistance	Rg	f = 1 MHz		1.1	1.6	2.1	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	12	18	
Rise Time ^c	t _r	$\label{eq:V_DD} \begin{array}{l} V_{\text{DD}} = 30 \; V, \; R_{\text{L}} = 30 \; \Omega \\ I_{\text{D}} \cong 1 \; A, \; V_{\text{GEN}} = 4.5 \; V, \; R_{\text{g}} = 1 \; \Omega \end{array}$		-	21	32	
Turn-Off Delay Time ^c	t _{d(off)}			-	8	12	ns
Fall Time ^c	t _f			-	7	11]
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	6.7	Α
Forward Voltage	V _{SD}	I _F = 0.8 A, V _{GS} = 0		-	0.8	1.2	V

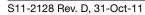
Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

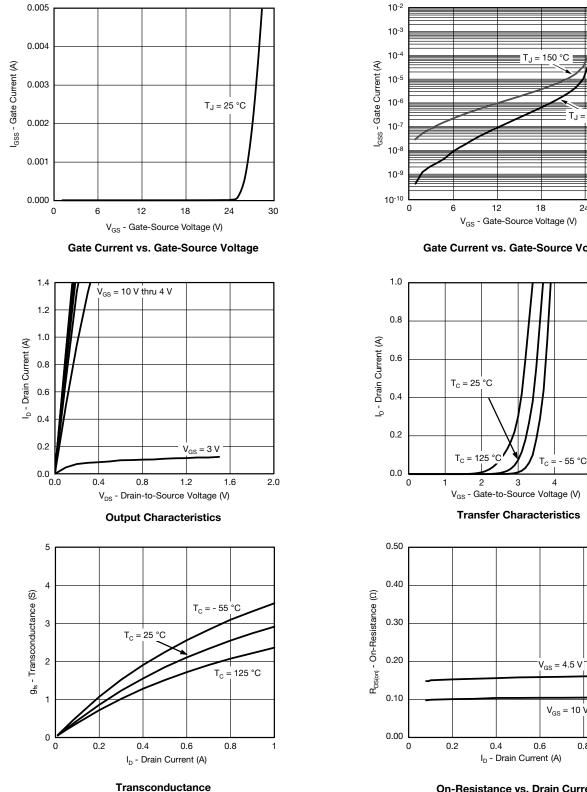
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

www.vishay.com





Vishay Siliconix

T_J = 25 °C

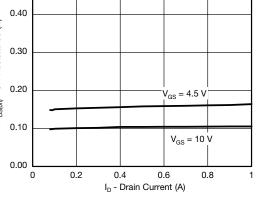
30

Transfer Characteristics

5

6

Document Number: 65730



On-Resistance vs. Drain Current

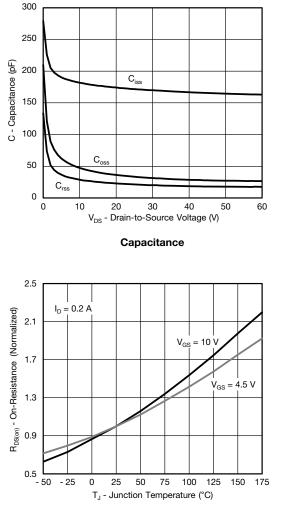
24 V_{GS} - Gate-Source Voltage (V)

Gate Current vs. Gate-Source Voltage

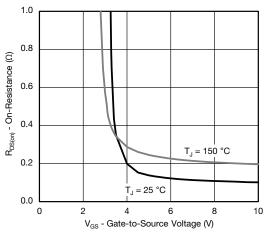


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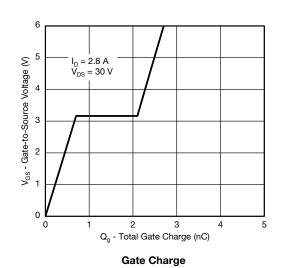
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

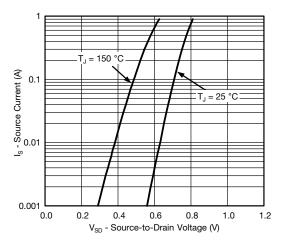


On-Resistance vs. Junction Temperature

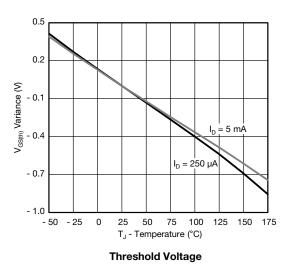


On-Resistance vs. Gate-to-Source Voltage





Source Drain Diode Forward Voltage



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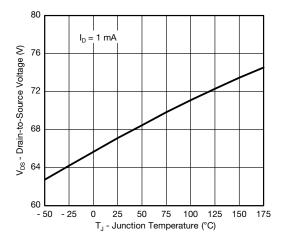
4

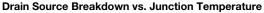
Document Number: 65730

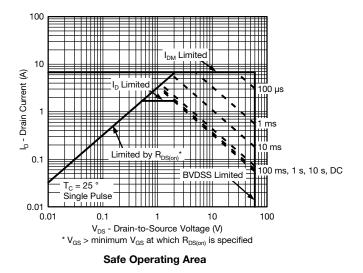


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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



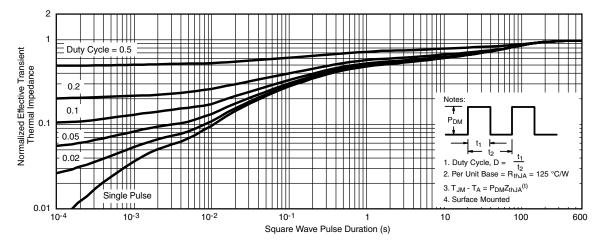




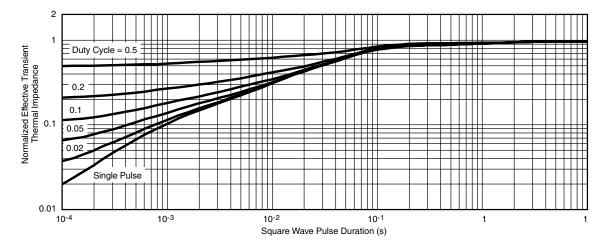


Vishay Siliconix

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65730.

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6



Package Information Vishay Siliconix

SC-70: 6-LEADS





	MILLIMETERS			RS INCHES		S
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	-	1.10	0.035	-	0.043
A ₁	-	-	0.10	-	-	0.004
A ₂	0.80	-	1.00	0.031	-	0.039
b	0.15	-	0.30	0.006	-	0.012
С	0.10	-	0.25	0.004	-	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е		0.65BSC			0.026BSC	;
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
٩	7°Nom				7°Nom	
ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5550						



Single-Channel LITTLE FOOT® SC-70 6-Pin MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance

INTRODUCTION

The new single 6-pin SC-70 package with a copper leadframe enables improved on-resistance values and enhanced thermal performance as compared to the existing 3-pin and 6-pin packages with Alloy 42 leadframes. These devices are intended for small to medium load applications where a miniaturized package is required. Devices in this package come in a range of on-resistance values, in n-channel and p-channel versions. This technical note discusses pin-outs, package outlines, pad patterns, evaluation board layout, and thermal performance for the single-channel version.

BASIC PAD PATTERNS

See Application Note 826, *Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs*, (http://www.vishay.com/doc?72286) for the basic pad layout and dimensions. These pad patterns are sufficient for the low to medium power applications for which this package is intended. Increasing the drain pad pattern yields a reduction in thermal resistance and is a preferred footprint. The availability of four drain leads rather than the traditional single drain lead allows a better thermal path from the package to the PCB and external environment.

PIN-OUT

Figure 1 shows the pin-out description and Pin 1 identification. The pin-out of this device allows the use of four pins as drain leads, which helps to reduce on-resistance and junction-to-ambient thermal resistance.

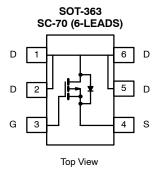


FIGURE 1.

For package dimensions see outline drawing SC-70 (6-Leads) (http://www.vishay.com/doc?71154)

EVALUATION BOARDS — SINGLE SC70-6

The evaluation board (EVB) measures 0.6 inches by 0.5 inches. The copper pad traces are the same as in Figure 2. The board allows examination from the outer pins to 6-pin DIP connections, permitting test sockets to be used in evaluation testing. See Figure 3.

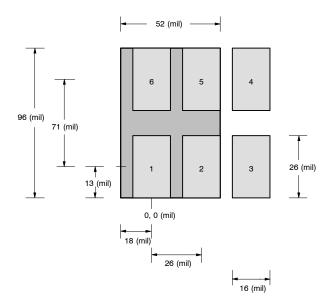


FIGURE 2. SC-70 (6 leads) Single

The thermal performance of the single 6-pin SC-70 has been measured on the EVB, comparing both the copper and Alloy 42 leadframes. This test was first conducted on the traditional Alloy 42 leadframe and was then repeated using the 1-inch² PCB with dual-side copper coating.

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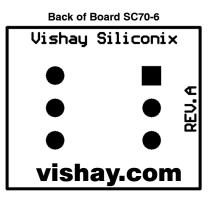


FIGURE 3.

THERMAL PERFORMANCE

Junction-to-Foot Thermal Resistance (Package Performance)

The junction to foot thermal resistance is a useful method of comparing different packages thermal performance.

A helpful way of presenting the thermal performance of the 6-Pin SC-70 copper leadframe device is to compare it to the traditional Alloy 42 version.

Thermal performance for the 6-pin SC-70 measured as junction-to-foot thermal resistance, where the "foot" is the drain lead of the device at the bottom where it meets the PCB. The junction-to-foot thermal resistance is typically 40°C/W in the copper leadframe and 163°C/W in the Alloy 42 leadframe — a four-fold improvement. This improved performance is obtained by the enhanced thermal conductivity of copper over Alloy 42.

Power Dissipation

The typical R θ_{JA} for the single 6-pin SC-70 with copper leadframe is 103°C/W steady-state, compared with 212°C/W for the Alloy 42 version. The figures are based on the 1-inch² FR4 test board. The following example shows how the thermal resistance impacts power dissipation for the two different leadframes at varying ambient temperatures.

ALLOY 42 LEADFRAME				
Room Ambient 25 °C	Elevated Ambient 60 °C			
$P_{D} = \frac{T_{J(max)} - T_{A}}{R\theta_{JA}}$	$P_{D} = \frac{T_{J(max)} - T_{A}}{R\theta_{JA}}$			
$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{212^{\circ}C/W}$	$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{212^{\circ}C/W}$			
$P_D = 590 \text{ mW}$	$P_{D} = 425 \text{ mW}$			

COOPER LEADFRAME				
Room Ambient 25 $^{\circ}$ C	Elevated Ambient 60 °C			
$P_{D} = \frac{T_{J(max)} - T_{A}}{R\theta_{JA}}$ $P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{124^{\circ}C/W}$	$P_{D} = \frac{T_{J(max)} - T_{A}}{R\theta_{JA}}$ $P_{D} = \frac{150^{\circ}C - 60^{\circ}C}{124^{\circ}C/W}$			
$P_{D} = 1.01 W$	$P_D = 726 \text{ mW}$			

As can be seen from the calculations above, the compact 6-pin SC-70 copper leadframe LITTLE FOOT power MOSFET can handle up to 1 W under the stated conditions.

Testing

To further aid comparison of copper and Alloy 42 leadframes, Figure 5 illustrates single-channel 6-pin SC-70 thermal performance on two different board sizes and two different pad patterns. The measured steady-state values of $R\theta_{JA}$ for the two leadframes are as follows:

LITTLE FOOT 6-PIN SC-70 Alloy 42 Copper 1) Minimum recommended pad pattern on the EVB board V (see Figure 3. 329.7°C/W 208.5°C/W 2) Industry standard 1-inch² PCB with maximum copper both sides. 211.8°C/W 103.5°C/W

The results indicate that designers can reduce thermal resistance ($R\theta_{JA}$) by 36% simply by using the copper leadframe device rather than the Alloy 42 version. In this example, a 121°C/W reduction was achieved without an increase in board area. If increasing in board size is feasible, a further 105°C/W reduction could be obtained by utilizing a 1-inch² square PCB area.

The copper leadframe versions have the following suffix:

Single:	Si14xxEDH
Dual:	Si19xxEDH
Complementary:	Si15xxEDH



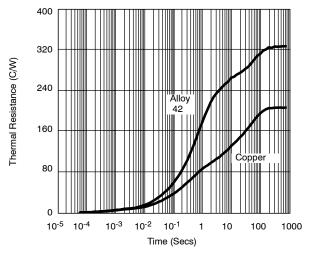
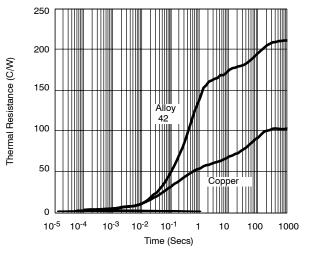


FIGURE 4. Leadframe Comparison on EVB





Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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